

Notice of References Cited

 Application/Control No.
 09/652,998

 Applicant(s)/Patent Under
 Reexamination
 DURCAN ET AL.

 Examiner
 Anh D. Mai

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 2814

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification	
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

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